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| Form PTO 1449 (Modified) | | U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE | | ATTY DOCKET NO. 239690US2RD | | SERIAL NO. 10/609392 NEW APPLICATION | |
| LIST OF REFERENCES CITED BY APPLICANT | | | | APPLICANT Jun YAMAUCHI, et al. | | | |
| | | | | FILING DATE HEREWITH 7/10/03 | | GROUP | |
| U.S. PATENT DOCUMENTS | | | | | | | |
| EXAMINER INITIAL | | DOCUMENT NUMBER | DATE | NAME | CLASS | SUB CLASS | FILING DATE IF APPROPRIATE |
| | AA | | | | | | |
| | AB | | | | | | |
| | AC | | | | | | |
| | AD | | | | | | |
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| | AM | | | | | | |
| | AN | | | | | | |
| FOREIGN PATENT DOCUMENTS | | | | | | | |
| | | DOCUMENT NUMBER | DATE | COUNTRY | TRANSLATION YES NO | | |
| | AO | 55-25492 | 07/04/80 | Japan (with English Abstract) | | | |
| | AP | 55-28215 | 07/26/80 | Japan (with English Abstract) | | | |
| | AQ | | | | | | |
| | AR | | | | | | |
| | AS | | | | | | |
| | AT | | | | | | |
| | AU | | | | | | |
| | AV | | | | | | |
| OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, etc.) | | | | | | | |
| | AW | Jun YAMAUCHI, et al., "First-Principles Study on Indium atoms in Silicon", 26 th INTERNATIONAL CONFERENCE ON PHYSICS OF SEMICONDUCTORS ABSTRACT, July 29, 2002, page 115 | | | | | |
| | AX | | | | | | |
| | AY | | | | | | |
| | AZ | | | | | <input type="checkbox"/> Additional References sheet(s) attached | |
| Examiner | | | | | Date Considered 8-20-04 | | |
| *Examiner: Initial if reference is considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. | | | | | | | |